

PC3H7J00000F Series

*4-channel package type is also available. (model No. **PC3Q67J0000F**)

Mini-flat Half Pitch Package, General Purpose Photocoupler



■ Description

PC3H7J00000F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin Mini-flat package, Half ptich type.

Input-output isolation voltage(rms) is 2.5kV.

Collector-emitter voltage is 80V and CTR is 20% to 400% at input current of 1mA.

■ Features

- 1. 4-pin Mini-flat Half pitch package (Lead pitch : 1.27mm)
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}: 80V)
- 4. Current transfer ratio (CTR : MIN. 20% at $I_F=1mA$, $V_{CE}=5V$)
- 5. Several CTR ranks available
- 6. Isolation voltage between input and output ($V_{iso(rms)}$: 2.5kV)
- 7. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC3H7)
- 2. Approved by VDE, DIN EN60747-5-2^(*) (as an option), file No. 40009162 (as model No. **PC3H7**)
- 3. Package resin: UL flammability grade (94V-0)

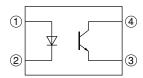
■ Applications

1. Programmable controllers

^(*) DIN EN60747-5-2: successor standard of DIN VDE0884



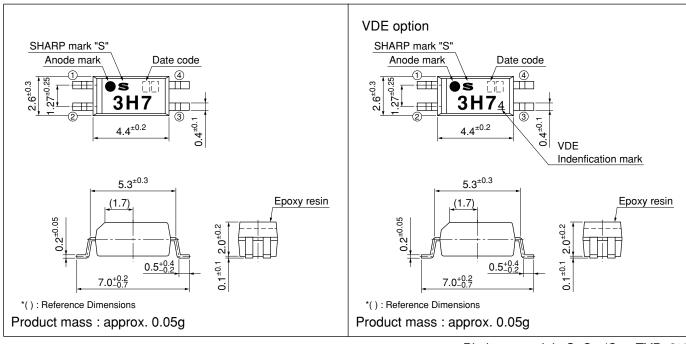
■ Internal Connection Diagram



- 1 Anode
- ② Cathode
- 3 Emitter
- 4 Collector

■ Outline Dimensions

(Unit: mm)



Plating material: SnCu (Cu: TYP. 2%)



Date code (2 digit)

1st digit				2nd digit		
Year of production				Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Country of origin Japan

Rank mark Refer to the Model Line-up table



	■ Absolute Maximum Ratings $(T_a=25^{\circ}C)$							
	Parameter	Symbol	Rating	Unit				
	Forward current	I_{F}	50	mA				
Input	*1 Peak forward current	I_{FM}	1	A				
In	Reverse voltage	V_R	6	V				
	Power dissipation	P	70	mW				
	Collector-emitter voltage	V_{CEO}	80	V				
Output	Emitter-collector voltage	V_{ECO}	6	V				
	Collector current	I_{C}	50	mA				
	Collector power dissipation	P_{C}	150	mW				
	Total power dissipation	P_{tot}	170	mW				
Operating temperature		Topr	-30 to +100	°C				
Storage temperature		T_{stg}	-40 to +125	°C				
*2 Isolation voltage		V _{iso (rms)}	2.5	kV				
*3 Soldering temperature		T_{sol}	260	°C				

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

							(1_a-25C)	
Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		V_F	$I_F=20mA$	_	1.2	1.4	V
Input	Reverse Current		I_R	$V_R=4V$	_	_	10	μΑ
	Terminal capacitance		C_t	V=0, f=1kHz	_	30	250	pF
	Collector dark	current	I_{CEO}	V_{CE} =50V, I_F =0	_	_	100	nA
Output	Collector-emitter breakdown voltage		$\mathrm{BV}_{\mathrm{CEO}}$	$I_{C}=0.1 \text{ mA}, I_{F}=0$	80	_	_	V
	Emitter-collector breakdown voltage		BV_{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	_	_	V
Transfer characteristics	Collector current		I_{C}	$I_F=1mA$, $V_{CE}=5V$	0.2	-	4.0	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=20\text{mA}, I_C=1\text{mA}$	-	0.1	0.2	V
	Isolation resistance		$R_{\rm ISO}$	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
	Floating capacitance		C_{f}	V=0, f=1MHz	_	0.6	1.0	pF
		Rise time	t _r	V 2V I 2 A D 1000	_	4	18	μs
	Response time	Fall time	t_{f}	V_{CE} =2V, I_{C} =2mA, R_{L} =100 Ω	_	3	18	μs

^{*1} Pulse width≤100μs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f=60Hz *3 For 10s



■ Model Line-up

Package	Taping 3 000pcs/reel		Rank mark	I _C [mA] (I _F =1mA, V _{CE} =5V, T _a =25°C)	
DIN EN60747-5-2	Approved				
	PC3H7J00000F	PC3H7YJ0000F	with or without	0.2 to 4.0	
	PC3H7AJ0000F	PC3H7Y1J000F	A	0.35 to 0.7	
	PC3H7BJ0000F	PC3H7Y2J000F	В	0.5 to 1.0	
Model No.	PC3H7CJ0000F	PC3H7Y3J000F	С	0.8 to 1.6	
	PC3H7DJ0000F	PC3H7Y4J000F	D	1.2 to 2.4	
	PC3H7ABJ000F	PC3H7Y5J000F	A or B	0.35 to 1.0	
	PC3H7BCJ000F	PC3H7Y6J000F	B or C	0.5 to 1.6	
	PC3H7CDJ000F	PC3H7Y7J000F	C or D	0.8 to 2.4	
	PC3H7ACJ000F	PC3H7Y8J000F	A, B or C	0.35 to 1.6	
	PC3H7BDJ000F	PC3H7Y9J000F	B, C or D	0.5 to 2.4	
	PC3H7ADJ000F	PC3H7Y0J000F	A, B, C or D	0.35 to 2.4	

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs. Ambient Temperature

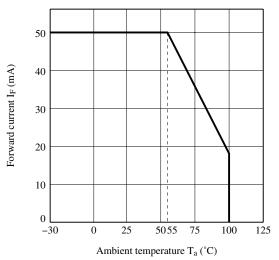


Fig.3 Collector Power Dissipation vs. Ambient Temperature

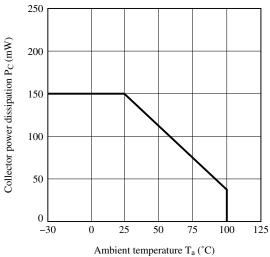


Fig.5 Peak Forward Current vs. Duty Ratio

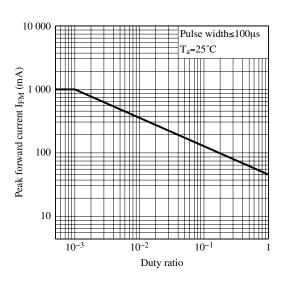


Fig.2 Diode Power Dissipation vs. Ambient Temperature

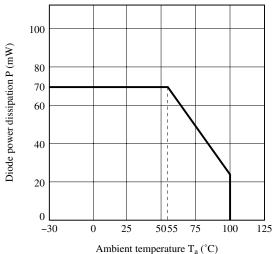


Fig.4 Total Power Dissipation vs. Ambient Temperature

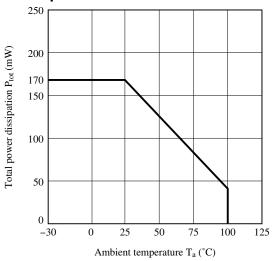


Fig.6 Forward Current vs. Forward Voltage

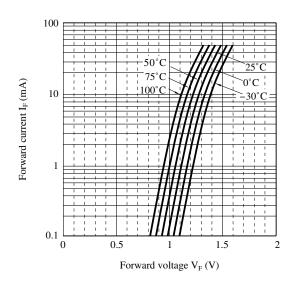




Fig.7 Current Transfer Ratio vs. Forward Current

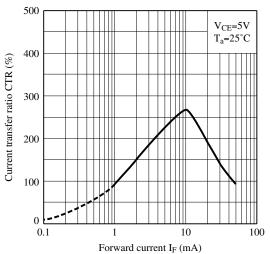


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

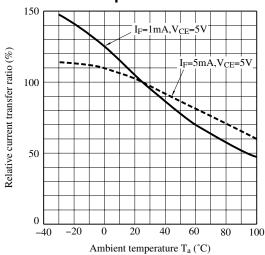


Fig.11 Collector Dark Current vs. Ambient Temperature

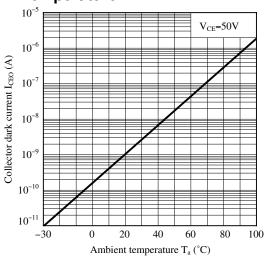


Fig.8 Collector Current vs. Collector-emitter Voltage

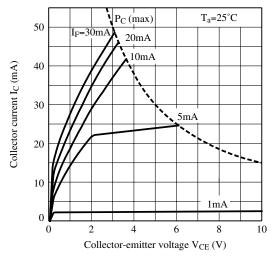


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

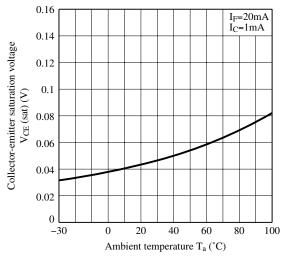


Fig.12 Response Time vs. Load Resistance

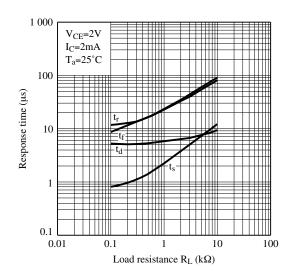
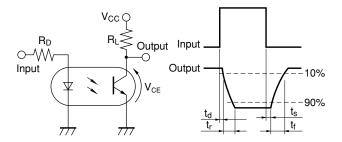


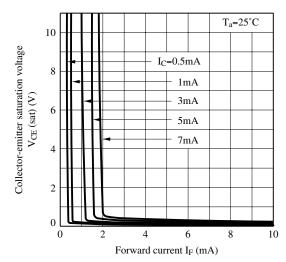


Fig.13 Test Circuit for Response Time



Please refer to the conditions in Fig.12

Fig.14 Collector-emitter Saturation Voltage vs. Forward Current



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

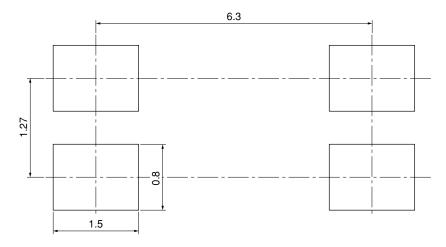
This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended Foot Print (reference)



(Unit:mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

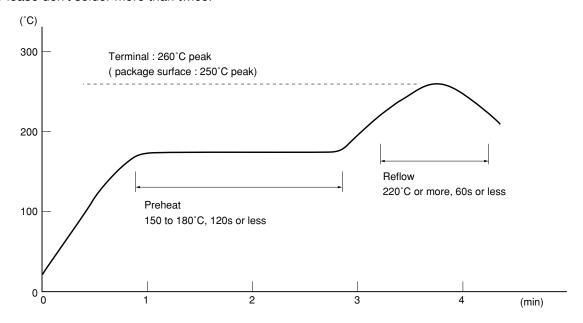
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 260°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

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■ Package specification

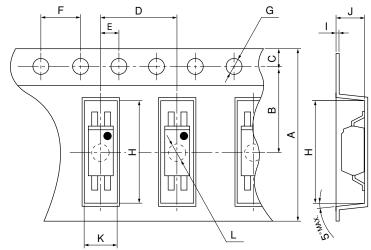
● Tape and Reel package

Package materials
Carrier tape : PS

Cover tape: PET (three layer system)

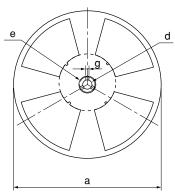
Reel: PS

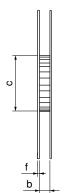
Carrier tape structure and Dimensions



Dimensions List (Unit: mm						
A	В	C	D	Е	F	G
12.0±0.3	5.5 ^{±0.1}	1.75 ^{±0.1}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 ^{+0.1}
Н	I	J	K	L		
7.5 ^{±0.1}	0.3±0.05	2.3±0.1	3.1±0.1	φ1.6 ^{+0.1}		

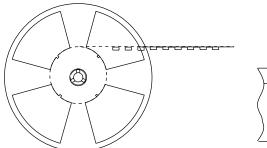
Reel structure and Dimensions

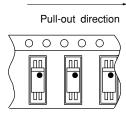




Dimension	ns List	(Unit: mm)			
a	b	с	d		
330	13.5 ^{±1.5}	100±1.0	13 ^{±0.5}		
e	f	g			
23 ^{±1.0}	2.0 ^{±0.5}	2.0 ^{±0.5}			

Direction of product insertion





[Packing: 3 000pcs/reel]



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